L Number	Hits	Search Text	DB	Time stamp
1	1	((high with voltage with well with (implant\$5 or form\$3))) and (low with	USPAT; US-PGPUB;	2003/12/16 19:55
		voltage with well with (implant\$5 or form\$3) with first) and photodiode and mems	EPO; JPO; DERWENT	13.33
2	5	((high with voltage with well with (implant\$5 or form\$3))) and (low with voltage with well with (implant\$5 or	USPAT; US-PGPUB; EPO; JPO;	2003/12/16 19:58
3	21	form\$3) with first) and photodiode ((high with voltage with well with (implant\$5 or form\$3))) and (low with voltage with well with (implant\$5 or	DERWENT USPAT; US-PGPUB; EPO; JPO;	2003/12/16 19:59
4	1	form\$3)) and photodiode ((high with voltage with well with (implant\$5 or form\$3))) and (low with voltage with well with (implant\$5 or	DERWENT USPAT; US-PGPUB; EPO; JPO;	2003/12/16 20:04
7	3	<pre>form\$3)) and photodiode and mems ((high with voltage with well with (implant\$5 or form\$3))) and (low with voltage with well with (implant\$5 or</pre>	DERWENT USPAT; US-PGPUB; EPO; JPO;	2003/12/16 20:10
8	21	form\$3)) and mems (high with voltage with well) and (low with voltage with well) and mems	DERWENT USPAT; US-PGPUB; EPO; JPO;	2003/12/16 21:35
9	1	(high adj voltage adj well) and (low adj voltage adj well) and mems	DERWENT USPAT; US-PGPUB; EPO; JPO;	2003/12/16 20:11
10	2	cmos same dmos same mems	DERWENT USPAT; US-PGPUB;	2003/12/16 21:04
11	10	cmos and dmos and mems	EPO; JPO; DERWENT USPAT; US-PGPUB;	2003/12/16 21:05
12	2420	mem same (accelerometer or sensor)	EPO; JPO; DERWENT USPAT; US-PGPUB; EPO; JPO;	2003/12/16 21:03
13	2420	mems same (accelerometer or sensor)	DERWENT USPAT; US-PGPUB; EPO; JPO;	2003/12/16 21:03
14	1862	mems with (accelerometer or sensor)	DERWENT USPAT; US-PGPUB; EPO; JPO;	2003/12/16 21:03
15	509	mems with accelerometer	DERWENT USPAT; US-PGPUB; EPO; JPO;	2003/12/16 21:03
16	2	cmos same dmos same photodiode	DERWENT USPAT; US-PGPUB; EPO; JPO;	2003/12/16 21:18
17	16	cmos and dmos and photodiode	DERWENT USPAT; US-PGPUB; EPO; JPO;	2003/12/16 21:05
18	31	cmos same dmos same soi	DERWENT USPAT; US-PGPUB; EPO; JPO;	2003/12/16 21:18
41	2	5578506.pn.	DERWENT USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/16 21:30

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46	2	5681761.pn.	USPAT;	2003/12/16
' '			US-PGPUB;	21:30
			EPO; JPO;	
			DERWENT	
47	113	(high with voltage with well) and (low	USPAT;	2003/12/16
	İ	with voltage with well) and photodiode	US-PGPUB;	21:36
			EPO; JPO;	
			DERWENT	
48	104		USPAT;	2003/12/16
		with voltage with well) and photodiode)	US-PGPUB;	21:47
		and @ad<20020222	EPO; JPO;	
1			DERWENT	/ /-
49	1		USPAT;	2003/12/16
		voltage adj well) and photodiode	US-PGPUB;	21:37
			EPO; JPO;	
50	71986	photodiode	DERWENT USPAT;	2003/12/16
30	/1900	photodrode	US-PGPUB;	21:48
			EPO; JPO;	21.40
			DERWENT	
51	67	photodiode and dmos	USPAT;	2003/12/16
1 -		F100 1 - 10 2 0 10 0 10 10 10 10 10 10 10 10 10 10 10	US-PGPUB;	21:48
			EPO; JPO;	
			DERWENT	
-	3203	438/22\$1.ccls. or 438/518.ccls. or	USPAT;	2003/12/16
		438/519.ccls. or 438/527.ccls.	US-PGPUB;	11:23
			EPO; JPO;	
			DERWENT	
-	18		USPAT;	2003/12/15
		438/519.ccls. or 438/527.ccls.) and (high	US-PGPUB;	17:46
		with voltage with (n adj well)) and (low	EPO; JPO;	
ļ	1	with voltage with (p adj well))	DERWENT	2002/12/16
_	1		USPAT;	2003/12/16
		with (n adj well)) and (low with voltage with (p adj well))	US-PGPUB; EPO; JPO;	11:21
		with (p ad) well))	DERWENT	1
-	70	(438/22\$1.ccls. or 438/518.ccls. or	USPAT;	2003/12/15
	'	438/519.ccls. or 438/527.ccls.) and (high	US-PGPUB;	18:40
		with voltage with well) and (low with	EPO; JPO;	1
		voltage with well)	DERWENT	1
-	68	((438/22\$1.ccls. or 438/518.ccls. or	USPAT;	2003/12/15
		438/519.ccls. or 438/527.ccls.) and (high	US-PGPUB;	17:47
		with voltage with well) and (low with	EPO; JPO;	
		voltage with well)) and (@ad<20020222 or	DERWENT	
		@rlad<20020222)		0000/10/15
_	324		USPAT;	2003/12/15
		with low with voltage with well) and	US-PGPUB;	19:55
		(second with low with voltage with well)	EPO; JPO;	
1_	39	((high with voltage with well) and (first	DERWENT USPAT;	2003/12/15
		with low with voltage with well) and	US-PGPUB;	19:29
		(second with low with voltage with well))	EPO; JPO;	
]	and (implant\$5 with (p adj (body or	DERWENT	
		region or well)))		
-	0	20030162375.URPN.	USPAT	2003/12/15
				18:43
_	44	257/548.ccls.	USPAT;	2003/12/15
			US-PGPUB;	19:13
			EPO; JPO;	
	[DERWENT	((
_	35	((high with voltage with well) and (first	USPAT;	2003/12/15
		with low with voltage with well) and	US-PGPUB;	19:29
		(second with low with voltage with well))	EPO; JPO;	
1		and (implant\$5 with p with high with voltage)	DERWENT	
_	7	<pre>voitage; ((first with mask\$3) same (implant\$5 with</pre>	USPAT;	2003/12/15
	[']	high with voltage with well)) and	US-PGPUB;	19:57
1		((second with mask\$3) same (first with	EPO; JPO;	15.57
		low with voltage with well))	DERWENT	
	L			L

-	2579	··· J·· ·· - · ·· - · · J · ·· - · · · - · · · - · · · ·	USPAT;	2003/12/16
ļ		(implant\$5 or form\$3)	US-PGPUB;	11:22
		•	EPO; JPO;	1
			DERWENT	
-	201	low with voltage with well with	USPAT;	2003/12/16
		(implant\$5 or form\$3) with first	US-PGPUB;	11:23
			EPO; JPO;	
			DERWENT	
_	196	low with voltage with well with	USPAT;	2003/12/16
	130	(implant\$5 or form\$3) with second	US-PGPUB;	11:23
		(Implanted) of formal) with second	EPO; JPO;	11.23
			1	
	114	(1-1-1	DERWENT	0000/10/16
_	114	(high with voltage with well with	USPAT;	2003/12/16
		(implant\$5 or form\$3)) and (low with	US-PGPUB;	11:23
		voltage with well with (implant\$5 or	EPO; JPO;	į l
		form\$3) with first) and (low with voltage	DERWENT	
		with well with (implant\$5 or form\$3) with		
1		second)		
-	3208	438/22\$1.ccls. or 438/518.ccls. or	USPAT;	2003/12/16
1		438/519.ccls. or 438/527.ccls.	US-PGPUB;	11:24
			EPO; JPO;	
			DERWENT	
1_	11	((high with voltage with well with	USPAT;	2003/12/16
		(implant\$5 or form\$3)) and (low with	US-PGPUB;	12:52
			EPO; JPO;	12.52
		voltage with well with (implant\$5 or		
		form\$3) with first) and (low with voltage	DERWENT	
		with well with (implant\$5 or form\$3) with		
		second)) and (438/22\$1.ccls. or		
		438/518.ccls. or 438/519.ccls. or]	
		438/527.ccls.)		/ /
-	6	((high with voltage with well with	USPAT;	2003/12/16
		(implant\$5 or form\$3)) and (low with	US-PGPUB;	12:42
		voltage with well with (implant\$5 or	EPO; JPO;	l
		form\$3) with first) and (low with voltage	DERWENT	
		with well with (implant\$5 or form\$3) with		
		second)) and cmos and dmos		
_	7		USPAT;	2003/12/16
		(implant\$5 or form\$3))) and (low with	US-PGPUB;	14:16
		voltage with well with (implant\$5 or	EPO; JPO;	
		form\$3) with first) and cmos and dmos	DERWENT	
1_	8	((high with voltage with well with	USPAT;	2003/12/16
		(implant\$5 or form\$3)) and (low with	US-PGPUB;	14:16
1		voltage with well with (implant\$5 or	EPO; JPO;	
		form\$3) with first) and (low with voltage	DERWENT	
			DEVMENT	
		with well with (implant\$5 or form\$3) with		
		second)) and (fifth with mask\$3)	Habbe	2002/12/16
-	144		USPAT;	2003/12/16
[(implant\$5 or form\$3))) and (low with	US-PGPUB;	13:13
		voltage with well with (implant\$5 or	EPO; JPO;	
		form\$3) with first)	DERWENT	
-	131	(((high with voltage with well with	USPAT;	2003/12/16
		(implant\$5 or form\$3))) and (low with	US-PGPUB;	13:13
]		voltage with well with (implant\$5 or	EPO; JPO;	
		form\$3) with first)) and (@ad<20020222 or	DERWENT	
		@rlad<20020222)		
-	1	((high with voltage with well with	USPAT;	2003/12/16
		(implant\$5 or form\$3)) and (low with	US-PGPUB;	19:53
		voltage with well with (implant\$5 or	EPO; JPO;	
		form\$3) with first) and (low with voltage	DERWENT	
		with well with (implant\$5 or form\$3) with]
		second)) and (fifth with photoresist with		
		film)		
		<u> </u>		1